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	DECLARATION FOR UTILITY OR				Attorney Docket Number	RDP:101 US		
DESIGN					First Named Inventor Michael P. Dunn			
	PATENT APPLICATION (37 CFR 1.63)				COMPLETE IF KNOWN			
		(37	CIR	FR 1.03)	Application Number			
⊠	Declaration Submitted	OR -	Declaration Submitted after Initial Filing (surcharge (37 CFR 1.16 (e))		Filing Date			
	with Initial			Group Art Unit				
	Filing			required)	Examiner Name			

	Fili	(37 CFR 1.16 (e)) required)		1			1		
	Filing			Examiner Name					
•	Express Mail Mailing Label No. EF155674309								
	As a below named inventor, I hereby declare that:								
	My residence, mailing address, and citizenship are as stated below next to my name.								
	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:								
	METHOD FOR MAKING A SILICON CARBIDE RESISTOR WITH SILICON/SILICON CARBIDE CONTACTS BY INDUCTION HEATING								
	the specification of which	:							
CCB	is attached hereto								
ı I	OR								
H	was filed on (MM/DD/YYYY) as United States Application Number or PCT International Application Number and was amended on (MM/DD/YYYY) (if applicable).								
the the term of the term	I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment specifically referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR 1.56, including for continuation-in-part applications, material information which became available between the filing date of the prior application and the national or PCT international filing date of the continuation-in-part application.								
	I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or (f) or 365(b) of any foreign application(s) for patent, inventor's or plant breeder's rights certificate(s), or 365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent, inventor's or plant breeder's rights certificate(s), or any PCT international application having a filing date before that of the application on which priority is claimed.								
	Prior Foreign Application Number(s)	Country		Filing Date D/YYYY)	Priority Not Claimed	Certified Copy YES	Attached? NO		
	☐ Additional foreign ap	plication numbers are listed			lata sheet PTO/SB/02	2B attached hereto:			
			Page	1 of 2]					

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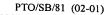
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DECLARATION – Utility or Design Patent Application

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Ì	ddress P.O. Box 10								
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Ì	Country U.S.A. Telepho			ne 716-433-1661				Fax 716-433-1665	
	be true; and further that these statements were made wi imprisonment, or both, under 18 U.S.C. 1001 and that s thereon.	own know th the kno	ledge are owledge t	true hat w	and that all s	atements	and the like	nformation and belief are believed to e so made are punishable by fine or	
	NAME OF SOLE OR FIRST INVENTOR				A petition	n has be	en filed f	or this unsigned inventor	
	Given Name (first and middle [if any]) Michael P.				mily Name Surname	Dunn	,		
F. F.	Inventor's Signature) Jus	nn				Date 1/1/02	
	Residence: City Clarence Center State NY Country US Citizenship US							Citizenship US	
	Mailing Address 9306 Pine Breeze La	ne							
T.	City Clarence Center State NY		ZIP	140)32		Country	y US	
	NAME OF SECOND INVENTOR:			A petition has been filed for this unsigned inventor					
	Given Name (first and middle [if any]) Brian M.		1	Family Name or Surname Tierney			ey		
	Inventor's Buin M Tierre						Date 1/7/02		
	Residence: City Newfane	State	NY		Country	US		Citizenship US	
	Mailing Address 4851 Shadigee Road								
	City Newfane State NY			141			Country	y US PTO/SB/02A attached hereto	



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POWER OF ATTORNEY OR AUTHORIZATION OF AGENT

Application Number	
Filing Date	
First Named Inventor	Michael P. Dunn
Title	Method for Making a Silicon Carbide Resistor with Silicon/Silicon Carbide
Group Art Unit	
Examiner Name	
Attorney Docket Number	RDP:101 US

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	Practitioner(s) named below:								
	Name			egistration Num	iber				
-Ē	Michael L. Dunn		25,330						
	Howard M. Ellis		25,856						
	Robert P. Simpson		33,034						
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	Firm or Michael L. Dunn Individual Name Michael L. Dunn Dunn & Associates								
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1	Country	US		<u></u>		1			
Į	Telephone	716-433-1661	Fax	716-433-1665	5	*			
		the entire interest. See 37 CFR 3							
1	Statement under 37 CF	FR 3.73(b) is enclosed. (Form P							
ļ		SIGNATURE of Applica	int or Assignee	of Record					
ļ	Name Michael F	P. Dunn)						
-	Signature	last f. De	unn						
-	Date //	17/02							
1	NOTE: Signatures of all the	inventors or assignees of record	I of the entire is	nterest or their	represent	ative(s) are required.			
L	Submit multiple forms if mor	re than one signature is required,	, see below*.						
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	Application Number	out diffess it contains a valid OMB donirol number	
	Filing Date		
POWER OF ATTORNEY OR	First Named Inventor	Michael P. Dunn	
AUTHORIZATION OF AGENT	Title	Method for Making a Silican Carbide Resistor with Silican/Silican Carbide	
TO THORIZATION OF AGENT	Group Art Unit	PROGRAMINATION CONTRACTOR OF THE PROGRAM CON	
·	Examiner Name		
**************************************	Attorney Docket Number	RDP:101 US	

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Howard M. Ellis			25,856				
Robert P. Simps	on		33,034				
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Firm or		Michael L. Dunn					
Individue	al Name	Dunn & Associates					
Address		P.O. Box 10					
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Country		US		110W AVIE	Lip	14100	
Telephone		716-433-1661	Fax	716-433-1665			
I am the:				1 /10 -100			
Applicant/I	nventor.						
Assignee of Statement u	f record of ti	he entire interest. See in R. 3.73(b) is enclosed.	37 CFR 3.71.				
	17 th 1 th	SIGNATIDE of	(FORM FIUISDIYO).				
	T	DIGITA I URE UI	Applicant or Assigned	e of Record			
Name	Brian M.	Tierney					
Signature	Bu	m M I seems	u1				
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NOTE: Signature	s of all the i	nventors or assignees	of record of the entire i	interest or their r	epresent	ative(s) are required.	
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